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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	M32C/80
Core Size	16/32-Bit
Speed	32MHz
Connectivity	CANbus, I²C, IEBus, SIO, UART/USART
Peripherals	DMA, WDT
Number of I/O	85
Program Memory Size	320KB (320K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	24K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 26x10b; D/A 2x8b
Oscillator Type	Internal
Operating Temperature	-20°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-BQFP
Supplier Device Package	100-QFP (14x20)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/m30853fwfp-u5

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1. Overview

The M32C/85 group (M32C/85, M32C/85T) microcomputer is a single-chip control unit that utilizes high-performance silicon gate CMOS technology with the M32C/80 series CPU core. The M32C/85 group (M32C/85, M32C/85T) is available in 144-pin and 100-pin plastic molded LQFP/QFP packages.

With a 16-Mbyte address space, this microcomputer combines advanced instruction manipulation capabilities to process complex instructions by less bytes and execute instructions at higher speed.

It includes a multiplier and DMAC adequate for office automation, communication devices and industrial equipments, and other high-speed processing applications.

1.1 Applications

Automobiles, audio, cameras, office equipment, communications equipment, portable equipment, etc.

Table 1.2 M32C/85 Group (M32C/85, M32C/85T) Performance (100-Pin Package)

Characteristic		Performance	
		M32C/85	M32C/85T
CPU	Basic Instructions	108 instructions	
	Minimum Instruction Execution Time	31.3 ns (f(BCLK)=32 MHz, V_{CC1}=4.2 V to 5.5 V) 41.7 ns (f(BCLK)=24 MHz, V_{CC1}=3.0 V to 5.5 V)	31.3 ns (f(BCLK)=32 MHz, V_{CC1}=4.2 V to 5.5 V)
	Operating Mode	Single-chip mode, Memory expansion mode and Microprocessor mode	Single-chip mode
	Address Space	16 Mbytes	
	Memory Capacity	See Table 1.3	
Peripheral Function	I/O Port	87 I/O pins and 1 input pin	
	Multifunction Timer	Timer A: 16 bits x 5 channels, Timer B: 16 bits x 6 channels Three-phase motor control circuit	
	Intelligent I/O	Time measurement function or Waveform generating function: 16 bits x 8 channels Communication function (Clock synchronous serial I/O, Clock asynchronous serial I/O, HDLC data processing)	
	Serial I/O	5 Channels Clock synchronous serial I/O, Clock asynchronous serial I/O, IEBus(1), I^2C bus(2)	
	CAN Module	2 channels Supporting CAN 2.0B specification	
	A/D Converter	10-bit A/D converter: 1 circuit, 26 channels	
	D/A Converter	8 bits x 2 channels	
	DMAC	4 channels	
	DMAC II	Can be activated by all peripheral function interrupt sources Immediate transfer, Calculation transfer and Chain transfer functions	
	CRC Calculation Circuit	CRC-CCITT	
	X/Y Converter	16 bits x 16 bits	
	Watchdog Timer	15 bits x 1 channel (with prescaler)	
	Interrupt	39 internal and 8 external sources, 5 software sources Interrupt priority level: 7	
	Clock Generation Circuit	4 circuits Main clock oscillation circuit(*), Sub clock oscillation circuit(*), On-chip oscillator, PLL frequency synthesizer (*)Equipped with a built-in feedback resistor. Ceramic resonator or crystal oscillator must be connected externally	
	Oscillation Stop Detect Function	Main clock oscillation stop detect function	
	Voltage Detection Circuit	Available (optional)	Not available(4)
Electrical Characteristics	Supply Voltage	V_{CC1}=4.2 V to 5.5 V, V_{CC2}=3.0 V to V_{CC1} (f(BCLK)=32 MHz) V_{CC1}=3.0 V to 5.5 V, V_{CC2}=3.0 V to V_{CC1} (f(BCLK)=24 MHz)	V_{CC1}=V_{CC2}=4.2 V to 5.5 V, (f(BCLK)=32 MHz)(3)
	Power Consumption	28 mA (V_{CC1}=V_{CC2}=5 V, f(BCLK)=32 MHz) 22 mA (V_{CC1}=V_{CC2}=3.3 V, f(BCLK)=24 MHz) 10µA (V_{CC1}=V_{CC2}=5 V, f(BCLK)=32 kHz, in wait mode)	28 mA (V_{CC1}=V_{CC2}=5 V, f(BCLK)=32 MHz) 10µA (V_{CC1}=V_{CC2}=5 V, f(BCLK)=32 kHz, in wait mode)
Flash Memory	Program/Erase Supply Voltage	3.3 V ± 0.3 V or 5.0 V ± 0.5 V	5.0 V ± 0.5 V
	Program and Erase Endurance	100 times (all space)	
Operating Ambient Temperature		–20 to 85°C –40 to 85°C (optional)	–40 to 85°C (T version)
Package		100-pin plastic molded LQFP/QFP	

NOTES:
1. IEBus is a trademark of NEC Electronics Corporation.
2. I^2C bus is a trademark of Koninklijke Philips Electronics N. V.
3. The supply voltage of M32C/85T (High-reliability version) must be V_{CC1}=V_{CC2}.
4. The cold start-up/warm start-up determine function is available only at the user's option.

All options are on a request basis.

1.4 Product Information

Table 1.3 lists the product information. Figure 1.2 shows the product numbering system.

Table 1.3 M32C/85 Group (1) (M32C/85) **As of July, 2005**

Type Number	Package Type	ROM Capacity	RAM Capacity	Remarks
M30855FJGP	PLQP0144KA-A (144P6Q-A)	512K+4K	24K	Flash Memory
M30853FJGP	PLQP0100KB-A (100P6Q-A)			
M30853FJFP	PRQP0100JB-A (100P6S-A)			
M30855FHGP	PLQP0144KA-A (144P6Q-A)	384K+4K		
M30853FHGP	PLQP0100KB-A (100P6Q-A)			
M30853FHFP	PRQP0100JB-A (100P6S-A)			
M30855FWGP	PLQP0144KA-A (144P6Q-A)	320K+4K		
M30853FWGP	PLQP0100KB-A (100P6Q-A)			
M30853FWFP	PRQP0100JB-A (100P6S-A)			
M30855MW-XXXGP	PLQP0144KA-A (144P6Q-A)	320K		Mask ROM
M30853MW-XXXGP	PLQP0100KB-A (100P6Q-A)			
M30853MW-XXXFP	PRQP0100JB-A (100P6S-A)			

Table 1.3 M32C/85 Group (2) (T Version, M32C/85T) **As of July, 2005**

Type Number	Package Type	ROM Capacity	RAM Capacity	Remarks
M30855FJTGP	PLQP0144KA-A (144P6Q-A)	512K+4K	24K	Flash Memory T Version (High-reliability 85°C Version)
M30853FJTGP	PLQP0100KB-A (100P6Q-A)			
M30855FHTGP	PLQP0144KA-A (144P6Q-A)	384K+4K		
M30853FHTGP	PLQP0100KB-A (100P6Q-A)			
M30855FWTGP	PLQP0144KA-A (144P6Q-A)	320K+4K		
M30853FWTGP	PLQP0100KB-A (100P6Q-A)			

Table 1.5 Pin Characteristics for 100-Pin Package (Continued)

Package Pin No.		Control Pin	Port	Interrupt Pin	Timer Pin	UART/CAN Pin	Intelligent I/O Pin	Analog Pin	Bus Control Pin(1)
FP	GP								
51	49		$P4_3$						A_{19}
52	50		$P4_2$						A_{18}
53	51		$P4_1$						A_{17}
54	52		$P4_0$						A_{16}
55	53		$P3_7$						A_{15}(/D_{15})
56	54		$P3_6$						A_{14}(/D_{14})
57	55		$P3_5$						A_{13}(/D_{13})
58	56		$P3_4$						A_{12}(/D_{12})
59	57		$P3_3$						A_{11}(/D_{11})
60	58		$P3_2$						A_{10}(/D_{10})
61	59		$P3_1$						A_9(/D_9)
62	60	V_{CC2}							
63	61		$P3_0$						A_8(/D_8)
64	62	V_{SS}							
65	63		$P2_7$					$AN2_7$	A_7(/D_7)
66	64		$P2_6$					$AN2_6$	A_6(/D_6)
67	65		$P2_5$					$AN2_5$	A_5(/D_5)
68	66		$P2_4$					$AN2_4$	A_4(/D_4)
69	67		$P2_3$					$AN2_3$	A_3(/D_3)
70	68		$P2_2$					$AN2_2$	A_2(/D_2)
71	69		$P2_1$					$AN2_1$	A_1(/D_1)
72	70		$P2_0$					$AN2_0$	A_0(/D_0)
73	71		$P1_7$	$\overline{INT5}$					D_{15}
74	72		$P1_6$	$\overline{INT4}$					D_{14}
75	73		$P1_5$	$\overline{INT3}$					D_{13}
76	74		$P1_4$						D_{12}
77	75		$P1_3$						D_{11}
78	76		$P1_2$						D_{10}
79	77		$P1_1$						D_9
80	78		$P1_0$						D_8
81	79		$P0_7$					$AN0_7$	D_7
82	80		$P0_6$					$AN0_6$	D_6
83	81		$P0_5$					$AN0_5$	D_5
84	82		$P0_4$					$AN0_4$	D_4
85	83		$P0_3$					$AN0_3$	D_3
86	84		$P0_2$					$AN0_2$	D_2
87	85		$P0_1$					$AN0_1$	D_1
88	86		$P0_0$					$AN0_0$	D_0
89	87		$P10_7$	$\overline{KI_3}$				AN_7	
90	88		$P10_6$	$\overline{KI_2}$				AN_6	
91	89		$P10_5$	$\overline{KI_1}$				AN_5	
92	90		$P10_4$	$\overline{KI_0}$				AN_4	
93	91		$P10_3$					AN_3	
94	92		$P10_2$					AN_2	
95	93		$P10_1$					AN_1	
96	94	AV_{SS}							
97	95		$P10_0$					AN_0	
98	96	V_{REF}							
99	97	AV_{CC}							
100	98		$P9_7$			RxD4/SCL4/STxD4		$\overline{ADTRG}$	

NOTES:

1. Bus control pins in M32C/85T cannot be used.

4. Special Function Registers (SFR)

Address	Register	Symbol	Value after RESET
000016			
000116			
000216			
000316			
000416	Processor Mode Register(1)	PM0	1000 00002(CNVss pin ="L") 0000 00112(CNVss pin ="H")
000516	Processor Mode Register 1	PM1	0016
000616	System Clock Control Register 0	CM0	0000 10002
000716	System Clock Control Register 1	CM1	0010 00002
000816			
000916	Address Match Interrupt Enable Register	AIER	0016
000A16	Protect Register	PRCR	XXXX 00002
000B16	External Data Bus Width Control Register(2)	DS	XXXX 10002(BYTE pin ="L") XXXX 00002(BYTE pin ="H")
000C16	Main Clock Division Register	MCD	XXX0 10002
000D16	Oscillation Stop Detection Register	CM2	0016
000E16	Watchdog Timer Start Register	WDTS	XX16
000F16	Watchdog Timer Control Register	WDC	000X XXXX2
001016 001116 001216	Address Match Interrupt Register 0	RMAD0	00000016
001316	Processor Mode Register 2	PM2	0016
001416 001516 001616	Address Match Interrupt Register 1	RMAD1	00000016
001716	Voltage Detection Register 2(2)	VCR2	0016
001816 001916 001A16	Address Match Interrupt Register 2	RMAD2	00000016
001B16	Voltage Detection Register 1(2)	VCR1	0000 10002
001C16 001D16 001E16	Address Match Interrupt Register 3	RMAD3	00000016
001F16			
002016			
002116			
002216			
002316			
002416			
002516			
002616	PLL Control Register 0	PLC0	0001 X0102
002716	PLL Control Register 1	PLC1	000X 00002
002816 002916 002A16	Address Match Interrupt Register 4	RMAD4	00000016
002B16			
002C16 002D16 002E16	Address Match Interrupt Register 5	RMAD5	00000016
002F16	Low Voltage Detection Interrupt Register(2)	D4INT	0016

X: Indeterminate

Blank spaces are reserved. No access is allowed.

NOTES:

1. The PM01 and PM00 bits in the PM0 register maintain values set before reset, even after software reset or watch-dog timer reset has been performed.
2. These registers in M32C/85T cannot be used.

Address	Register	Symbol	Value after RESET
0030₁₆			
0031₁₆			
0032₁₆			
0033₁₆			
0034₁₆			
0035₁₆			
0036₁₆			
0037₁₆			
0038₁₆ 0039₁₆ 003A₁₆	Address Match Interrupt Register 6	RMAD6	000000₁₆
003B₁₆			
003C₁₆ 003D₁₆ 003E₁₆	Address Match Interrupt Register 7	RMAD7	000000₁₆
003F₁₆			
0040₁₆			
0041₁₆			
0042₁₆			
0043₁₆			
0044₁₆			
0045₁₆			
0046₁₆			
0047₁₆			
0048₁₆	External Space Wait Control Register 0(1)	EWCR0	X0X0 0011₂
0049₁₆	External Space Wait Control Register 1(1)	EWCR1	X0X0 0011₂
004A₁₆	External Space Wait Control Register 2(1)	EWCR2	X0X0 0011₂
004B₁₆	External Space Wait Control Register 3(1)	EWCR3	X0X0 0011₂
004C₁₆			
004D₁₆			
004E₁₆			
004F₁₆			
0050₁₆			
0051₁₆			
0052₁₆			
0053₁₆			
0054₁₆			
0055₁₆	Flash Memory Control Register 1	FMR1	0000 0101₂
0056₁₆			
0057₁₆	Flash Memory Control Register 0	FMR0	0000 0001₂(Flash memory version) XXXX XXX0₂(Masked ROM version)
0058₁₆			
0059₁₆			
005A₁₆			
005B₁₆			
005C₁₆			
005D₁₆			
005E₁₆			
005F₁₆			

X: Indeterminate

Blank spaces are reserved. No access is allowed.

NOTES:

1. These registers cannot be used in M32C/85T.

Address	Register	Symbol	Value after RESET
00F016	Data Compare Register 00	G0CMP0	XX16
00F116	Data Compare Register 01	G0CMP1	XX16
00F216	Data Compare Register 02	G0CMP2	XX16
00F316	Data Compare Register 03	G0CMP3	XX16
00F416	Data Mask Register 00	G0MSK0	XX16
00F516	Data Mask Register 01	G0MSK1	XX16
00F616	Communication Clock Select Register	CCS	XXXX 00002
00F716			
00F816	Receive CRC Code Register 0	G0RCRC	XX16
00F916			XX16
00FA16	Transmit CRC Code Register 0	G0TCRC	0016
00FB16			0016
00FC16	SI/O Extended Mode Register 0	G0EMR	0016
00FD16	SI/O Extended Receive Control Register 0	G0ERC	0016
00FE16	SI/O Special Communication Interrupt Detect Register 0	G0IRF	0016
00FF16	SI/O Extended Transmit Control Register 0	G0ETC	0000 0XXX2
010016	Time Measurement/Waveform Generating Register 10	G1TM0/G1PO0	XX16
010116			XX16
010216	Time Measurement/Waveform Generating Register 11	G1TM1/G1PO1	XX16
010316			XX16
010416	Time Measurement/Waveform Generating Register 12	G1TM2/G1PO2	XX16
010516			XX16
010616	Time Measurement/Waveform Generating Register 13	G1TM3/G1PO3	XX16
010716			XX16
010816	Time Measurement/Waveform Generating Register 14	G1TM4/G1PO4	XX16
010916			XX16
010A16	Time Measurement/Waveform Generating Register 15	G1TM5/G1PO5	XX16
010B16			XX16
010C16	Time Measurement/Waveform Generating Register 16	G1TM6/G1PO6	XX16
010D16			XX16
010E16	Time Measurement/Waveform Generating Register 17	G1TM7/G1PO7	XX16
010F16			XX16
011016	Waveform Generating Control Register 10	G1POCR0	0000 X0002
011116	Waveform Generating Control Register 11	G1POCR1	0X00 X0002
011216	Waveform Generating Control Register 12	G1POCR2	0X00 X0002
011316	Waveform Generating Control Register 13	G1POCR3	0X00 X0002
011416	Waveform Generating Control Register 14	G1POCR4	0X00 X0002
011516	Waveform Generating Control Register 15	G1POCR5	0X00 X0002
011616	Waveform Generating Control Register 16	G1POCR6	0X00 X0002
011716	Waveform Generating Control Register 17	G1POCR7	0X00 X0002
011816	Time Measurement Control Register 10	G1TMCR0	0016
011916	Time Measurement Control Register 11	G1TMCR1	0016
011A16	Time Measurement Control Register 12	G1TMCR2	0016
011B16	Time Measurement Control Register 13	G1TMCR3	0016
011C16	Time Measurement Control Register 14	G1TMCR4	0016
011D16	Time Measurement Control Register 15	G1TMCR5	0016
011E16	Time Measurement Control Register 16	G1TMCR6	0016
011F16	Time Measurement Control Register 17	G1TMCR7	0016

X: Indeterminate

Blank spaces are reserved. No access is allowed.

Address	Register	Symbol	Value after RESET
0150₁₆			
0151₁₆			
0152₁₆			
0153₁₆			
0154₁₆			
0155₁₆			
0156₁₆			
0157₁₆			
0158₁₆			
0159₁₆			
015A₁₆			
015B₁₆			
015C₁₆			
015D₁₆			
015E₁₆			
015F₁₆			
0160₁₆			
0161₁₆			
0162₁₆			
0163₁₆			
0164₁₆			
0165₁₆			
0166₁₆			
0167₁₆			
0168₁₆			
0169₁₆			
016A₁₆			
016B₁₆			
016C₁₆			
016D₁₆			
016E₁₆			
016F₁₆			
0170₁₆			
0171₁₆			
0172₁₆			
0173₁₆			
0174₁₆			
0175₁₆			
0176₁₆			
0177₁₆			
0178₁₆	Input Function Select Register	IPS	00₁₆
0179₁₆	Input Function Select Register A	IPSA	00₁₆
017A₁₆			
017B₁₆			
017C₁₆			
017D₁₆ to 01DF₁₆			

X: Indeterminate

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<144-pin package>

Address	Register	Symbol	Value after RESET
03A0$_{16}$	Function Select Register A8	PS8	X000 0000$_2$
03A1$_{16}$	Function Select Register A9	PS9	00$_{16}$
03A2$_{16}$			
03A3$_{16}$			
03A4$_{16}$			
03A5$_{16}$			
03A6$_{16}$			
03A7$_{16}$	Function Select Register D1	PSD1	X0XX XX00$_2$
03A8$_{16}$			
03A9$_{16}$			
03AA$_{16}$			
03AB$_{16}$			
03AC$_{16}$	Function Select Register C2	PSC2	XXXX X00X$_2$
03AD$_{16}$	Function Select Register C3	PSC3	X0XX XXXX$_2$
03AE$_{16}$			
03AF$_{16}$	Function Select Register C	PSC	00X0 0000$_2$
03B0$_{16}$	Function Select Register A0	PS0	00$_{16}$
03B1$_{16}$	Function Select Register A1	PS1	00$_{16}$
03B2$_{16}$	Function Select Register B0	PSL0	00$_{16}$
03B3$_{16}$	Function Select Register B1	PSL1	00$_{16}$
03B4$_{16}$	Function Select Register A2	PS2	00X0 0000$_2$
03B5$_{16}$	Function Select Register A3	PS3	00$_{16}$
03B6$_{16}$	Function Select Register B2	PSL2	00X0 0000$_2$
03B7$_{16}$	Function Select Register B3	PSL3	00$_{16}$
03B8$_{16}$			
03B9$_{16}$	Function Select Register A5	PS5	XXX0 0000$_2$
03BA$_{16}$			
03BB$_{16}$			
03BC$_{16}$			
03BD$_{16}$			
03BE$_{16}$			
03BF$_{16}$			
03C0$_{16}$	Port P6 Register	P6	XX$_{16}$
03C1$_{16}$	Port P7 Register	P7	XX$_{16}$
03C2$_{16}$	Port P6 Direction Register	PD6	00$_{16}$
03C3$_{16}$	Port P7 Direction Register	PD7	00$_{16}$
03C4$_{16}$	Port P8 Register	P8	XX$_{16}$
03C5$_{16}$	Port P9 Register	P9	XX$_{16}$
03C6$_{16}$	Port P8 Direction Register	PD8	00X0 0000$_2$
03C7$_{16}$	Port P9 Direction Register	PD9	00$_{16}$
03C8$_{16}$	Port P10 Register	P10	XX$_{16}$
03C9$_{16}$	Port P11 Register	P11	XX$_{16}$
03CA$_{16}$	Port P10 Direction Register	PD10	00$_{16}$
03CB$_{16}$	Port P11 Direction Register	PD11	XXX0 0000$_2$
03CC$_{16}$	Port P12 Register	P12	XX$_{16}$
03CD$_{16}$	Port P13 Register	P13	XX$_{16}$
03CE$_{16}$	Port P12 Direction Register	PD12	00$_{16}$
03CF$_{16}$	Port P13 Direction Register	PD13	00$_{16}$

X: Indeterminate

Blank spaces are reserved. No access is allowed.

$V_{CC1}=V_{CC2}=5V$

Table 5.3 Electrical Characteristics

($V_{CC1}=V_{CC2}=4.2$ to 5.5V, $V_{SS}=0V$ at Topr= –20 to 85°C, f(BCLK)=32MHz unless otherwise specified)

Symbol	Parameter		Condition	Standard			Unit
				Min.	Typ.	Max.	
V_{OH}	Output High ("H") Voltage	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$	I_{OH}=-5mA	V_{CC2}-2.0		V_{CC2}	V
		$P6_0$-$P6_7$, $P7_2$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1)	I_{OH}=-5mA	V_{CC1}-2.0		V_{CC1}	
		$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$	I_{OH}=-200µA	V_{CC2}-0.3		V_{CC2}	V
		$P6_0$-$P6_7$, $P7_2$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$,$P14_0$-$P14_6$, $P15_0$-$P15_7$(1)	I_{OH}=-200µA	V_{CC1}-0.3		V_{CC1}	
		X_{OUT}	I_{OH}=-1mA	3.0		V_{CC1}	V
		X_{COUT} High Power	No load applied		2.5		V
		X_{COUT} Low Power	No load applied		1.6		
V_{OL}	Output Low ("L") Voltage	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_0$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1)	I_{OL}=5mA			2.0	V
		$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_0$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1)	I_{OL}=200µA			0.45	V
		X_{OUT}	I_{OL}=1mA			2.0	V
		X_{COUT} High Power	No load applied		0		V
		X_{COUT} Low Power	No load applied		0		
V_{T+}-V_{T-}	Hysteresis	$\overline{HOLD}$, $\overline{RDY}$, $TA0_{IN}$-$TA4_{IN}$, $TB0_{IN}$-$TB5_{IN}$, $\overline{INT0}$-$\overline{INT5}$, $\overline{ADTRG}$, $\overline{CTS0}$-$\overline{CTS4}$, CLK0-CLK4, $TA0_{OUT}$-$TA4_{OUT}$, $\overline{NMI}$, $\overline{KI0}$-$\overline{KI3}$, RxD0-RxD4, SCL0-SCL4, SDA0-SDA4		0.2		1.0	V
		$\overline{RESET}$		0.2		1.8	V
I_{IH}	Input High ("H") Current	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_0$-$P7_7$, $P8_0$-$P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1), X_{IN}, $\overline{RESET}$, CNV_{SS}, BYTE	V_I=5V			5.0	µA
I_{IL}	Input Low ("L") Current	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_0$-$P7_7$, $P8_0$-$P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1), X_{IN}, $\overline{RESET}$, CNV_{SS}, BYTE	V_I=0V			-5.0	µA
R_{PULLUP}	Pull-up Resistance	$P0_0$-$P0_7$, $P1_0$-$P1_7$, $P2_0$-$P2_7$, $P3_0$-$P3_7$, $P4_0$-$P4_7$, $P5_0$-$P5_7$, $P6_0$-$P6_7$, $P7_2$-$P7_7$, $P8_0$-$P8_4$, $P8_6$, $P8_7$, $P9_0$-$P9_7$, $P10_0$-$P10_7$, $P11_0$-$P11_4$, $P12_0$-$P12_7$, $P13_0$-$P13_7$, $P14_0$-$P14_6$, $P15_0$-$P15_7$(1)	V_I=0V Flash Memory	30	50	167	kΩ
			Masked ROM	20	40	167	
Rf_{XIN}	Feedback Resistance	X_{IN}			1.5		MΩ
Rf_{XCIN}	Feedback Resistance	X_{CIN}			10		MΩ
V_{RAM}	RAM Standby Voltage	In stop mode		2.0			V

NOTES:

1. P11 to P15 are provided in the 144-pin package only.

$V_{CC1}=V_{CC2}=5V$

Switching Characteristics

(V_{CC1} = V_{CC2} = 4.2 to 5.5V, V_{SS} = 0V at Topr = –20 to 85°C unless otherwise specified)

Table 5.22 Memory Expansion Mode and Microprocessor Mode (when accessing external memory space)

Symbol	Parameter	Measurement Condition	Standard		Unit
			Min.	Max.	
$t_{d(BCLK-AD)}$	Address Output Delay Time	See Figure 5.2		18	ns
$t_{h(BCLK-AD)}$	Address Output Hold Time (BCLK standard)		-3		ns
$t_{h(RD-AD)}$	Address Output Hold Time (RD standard)(3)		0		ns
$t_{h(WR-AD)}$	Address Output Hold Time (WR standard)(3)		(Note 1)		ns
$t_{d(BCLK-CS)}$	Chip-Select Signal Output Delay Time			18	ns
$t_{h(BCLK-CS)}$	Chip-Select Signal Output Hold Time (BCLK standard)		-3		ns
$t_{h(RD-CS)}$	Chip-Select Signal Output Hold Time (RD standard)(3)		0		ns
$t_{h(WR-CS)}$	Chip-Select Signal Output Hold Time (WR standard)(3)		(Note 1)		ns
$t_{d(BCLK-RD)}$	RD Signal Output Delay Time			18	ns
$t_{h(BCLK-RD)}$	RD Signal Output Hold Time		-5		ns
$t_{d(BCLK-WR)}$	WR Signal Output Delay Time			18	ns
$t_{h(BCLK-WR)}$	WR Signal Output Hold Time		-5		ns
$t_{d(DB-WR)}$	Data Output Delay Time (WR standard)		(Note 2)		ns
$t_{h(WR-DB)}$	Data Output Hold Time (WR standard)(3)		(Note 1)		ns
$t_{w(WR)}$	WR Output Width		(Note 2)		ns

NOTES:

1. Values can be obtained from the following equations, according to BCLK frequency.

$$t_{h(WR-DB)} = \frac{10^9}{f_{(BCLK)} \times 2} - 10 \quad [ns]$$

$$t_{h(WR-AD)} = \frac{10^9}{f_{(BCLK)} \times 2} - 10 \quad [ns]$$

$$t_{h(WR-CS)} = \frac{10^9}{f_{(BCLK)} \times 2} - 10 \quad [ns]$$

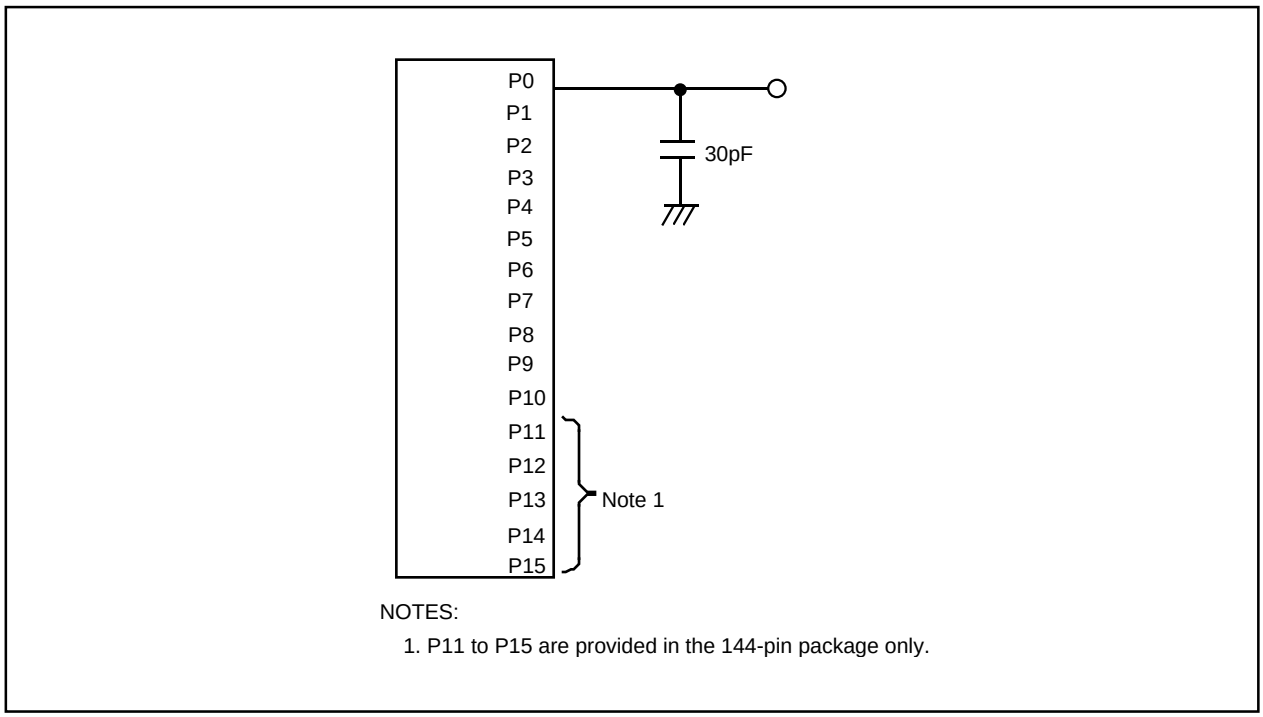
2. Values can be obtained from the following equations, according to BCLK frequency and external bus cycles.

$$t_{w(WR)} = \frac{10^9 \times n}{f_{(BCLK)} \times 2} - 15 \quad [ns]$$ (if external bus cycle is aϕ + bϕ, n=(bx2)-1)

$$t_{d(DB-WR)} = \frac{10^9 \times m}{f_{(BCLK)}} - 20 \quad [ns]$$ (if external bus cycle is aϕ + bϕ, m= b)

3. *tc* ns is added when recovery cycle is inserted.

$V_{CC1}=V_{CC2}=5V$



NOTES:
1. P11 to P15 are provided in the 144-pin package only.

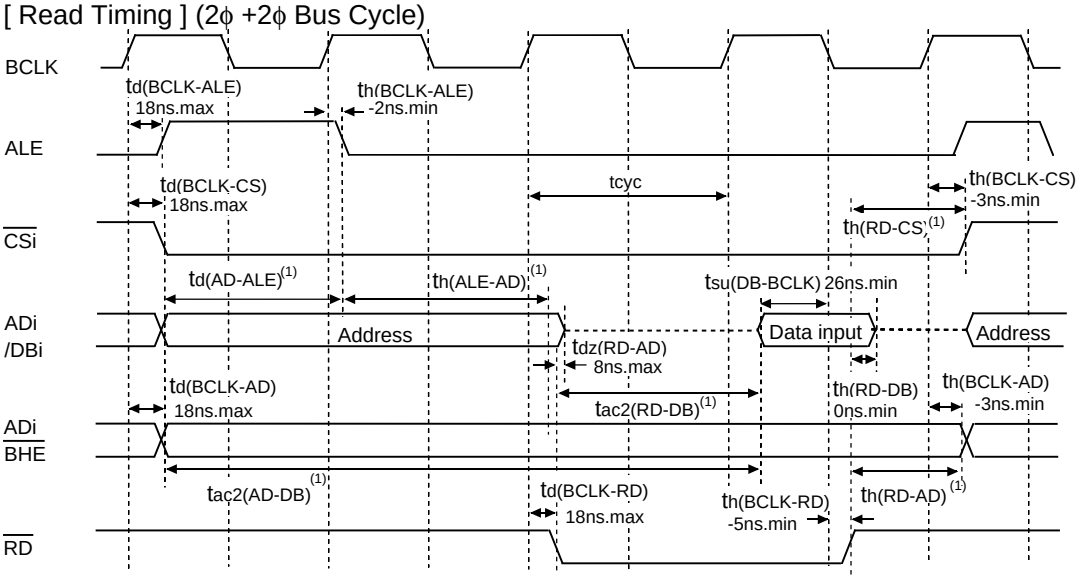
Figure 5.2 P0 to P15 Measurement Circuit

$V_{CC1}=V_{CC2}=5V$

Memory Expansion Mode and Microprocessor Mode

(when accessing an external memory space with the multiplexed bus)

[Read Timing] (2φ +2φ Bus Cycle)



NOTES:

1. Varies with operation frequency:

$t_{d(AD-ALE)}$=(tcyc/2 x n-20)ns.min (if external bus cycle is aφ + bφ, n=a)

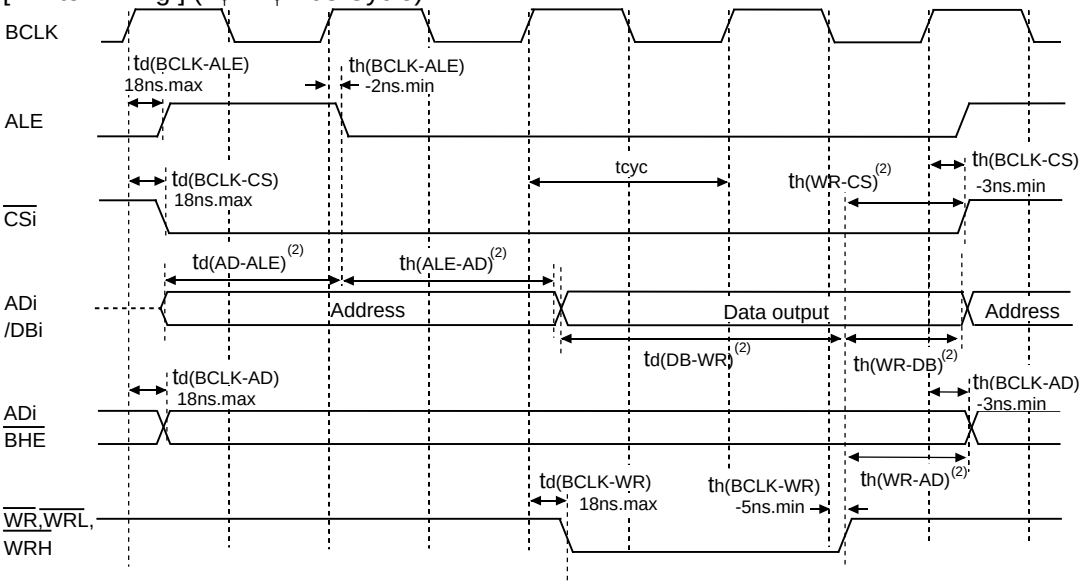
$t_{h(ALE-AD)}$=(tcyc/2 x n-10)ns.min (if external bus cycle is aφ + bφ, n=a)

$t_{h(RD-AD)}$=(tcyc/2-10)ns.min, $t_{h(RD-CS)}$=(tcyc/2-10)ns.min

$t_{ac2(RD-DB)}$=(tcyc/2 x m-35)ns.max (if external bus cycle is aφ + bφ, m=(b x 2)-1)

$t_{ac2(AD-DB)}$=(tcyc/2 x p-35)ns.max (if external bus cycle is aφ + bφ, p={(a+b-1) x 2}+1)

[Write Timing] (2φ +2φ Bus Cycle)



NOTES:

2. Varies with operation frequency:

$t_{d(AD-ALE)}$=(tcyc/2 x n - 20)ns.min

(if external bus cycle is aφ + bφ, n=a)

$t_{h(ALE-AD)}$=(tcyc/2 x n -10)ns.min

(if external bus cycle is aφ + bφ, n=a)

$t_{h(WR-AD)}$=(tcyc/2-10)ns.min,

$t_{h(WR-CS)}$=(tcyc/2-10)ns.min, $t_{h(WR-DB)}$=(tcyc/2-10)ns.min

$t_{d(DB-WR)}$=(tcyc/2 x m-25)ns.min

(if external bus cycle is aφ + bφ, m=(b x 2)-1)

Measurement Conditions:

- $V_{CC1}=V_{CC2}$=4.2 to 5.5V
- Input high and low voltage: V_{IH}=2.5V, V_{IL}=0.8V
- Output high and low voltage: V_{OH}=2.0V, V_{OL}=0.8V

$$tcyc=\frac{10^9}{f_{(BCLK)}}$$

Figure 5.4 $V_{CC1}=V_{CC2}$=5V Timing Diagram (2)

$V_{CC1}=V_{CC2}=3.3V$

Table 5.25 A/D Conversion Characteristics ($V_{CC1}=V_{CC2}=AV_{CC}=V_{REF}$= 3.0 to 3.6V, $V_{SS}=AV_{SS}$=0V at Topr = –20 to 85°C, f(BCLK) = 24MHz unless otherwise specified)

Symbol	Parameter		Measurement Condition	Standard			Unit
				Min.	Typ.	Max.	
-	Resolution		$V_{REF}=V_{CC1}$			10	Bits
INL	Integral Nonlinearity Error	No S&H (8-bit)	$V_{CC1}=V_{CC2}=V_{REF}$=3.3V			±2	LSB
DNL	Differential Nonlinearity Error	No S&H (8-bit)				±1	LSB
-	Offset Error	No S&H (8-bit)				±2	LSB
-	Gain Error	No S&H (8-bit)				±2	LSB
R_{LADDER}	Resistor Ladder		$V_{REF}=V_{CC1}$	8		40	kΩ
t_{CONV}	8-bit Conversion Time(1, 2)			6.1			µs
V_{REF}	Reference Voltage			3		V_{CC1}	V
V_{IA}	Analog Input Voltage			0		V_{REF}	V

S&H: Sample and Hold

NOTES:
1. Divide f(X_{IN}), if exceeding 10 MHz, to keep ϕAD frequency at 10 MHz or less.
2. S&H not available.

Table 5.26 D/A Conversion Characteristics ($V_{CC1}=V_{CC2}=V_{REF}$=3.0 to 3.6V, $V_{SS}=AV_{SS}$=0V at Topr = –20 to 85°C, f(BCLK) = 24MHz unless otherwise specified)

Symbol	Parameter	Measurement Condition	Standard			Unit
			Min.	Typ.	Max.	
-	Resolution				8	Bits
-	Absolute Accuracy				1.0	%
t_{SU}	Setup Time				3	µs
R_O	Output Resistance		4	10	20	kΩ
I_{VREF}	Reference Power Supply Input Current	(Note 1)			1.0	mA

NOTES:
1. Measurement results when using one D/A converter. The DAi register (i=0, 1) of the D/A converter, not being used, is set to "00_{16}". The resistor ladder in the A/D converter is excluded.
I_{VREF} flows even if the VCUT bit in the AD0CON1 register is set to "0" (no V_{REF} connection).

$V_{CC1}=V_{CC2}=3.3V$

Timing Requirements

($V_{CC1}=V_{CC2}$= 3.0 to 3.6V, V_{SS}= 0V at Topr = –20 to 85°C unless otherwise specified)

Table 5.29 Timer A Input (Count Source Input in Event Counter Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TA)}$	TAi_{IN} Input Cycle Time	100		ns
$t_{w(TAH)}$	TAi_{IN} Input High ("H") Width	40		ns
$t_{w(TAL)}$	TAi_{IN} Input Low ("L") Width	40		ns

Table 5.30 Timer A Input (Gate Input in Timer Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TA)}$	TAi_{IN} Input Cycle Time	400		ns
$t_{w(TAH)}$	TAi_{IN} Input High ("H") Width	200		ns
$t_{w(TAL)}$	TAi_{IN} Input Low ("L") Width	200		ns

Table 5.31 Timer A Input (External Trigger Input in One-Shot Timer Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TA)}$	TAi_{IN} Input Cycle Time	200		ns
$t_{w(TAH)}$	TAi_{IN} Input High ("H") Width	100		ns
$t_{w(TAL)}$	TAi_{IN} Input Low ("L") Width	100		ns

Table 5.32 Timer A Input (External Trigger Input in Pulse Width Modulation Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{w(TAH)}$	TAi_{IN} Input High ("H") Width	100		ns
$t_{w(TAL)}$	TAi_{IN} Input Low ("L") Width	100		ns

Table 5.33 Timer A Input (Counter Increment/decrement Input in Event Counter Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(UP)}$	TAi_{OUT} Input Cycle Time	2000		ns
$t_{w(UPH)}$	TAi_{OUT} Input High ("H") Width	1000		ns
$t_{w(UPL)}$	TAi_{OUT} Input Low ("L") Width	1000		ns
$t_{su(UP-TIN)}$	TAi_{OUT} Input Setup Time	400		ns
$t_{h(TIN-UP)}$	TAi_{OUT} Input Hold Time	400		ns

$V_{CC1}=V_{CC2}=3.3V$

Timing Requirements

($V_{CC1}=V_{CC2}$= 3.0 to 3.6V, V_{SS} = 0V at Topr = –20 to 85°C unless otherwise specified)

Table 5.34 Timer B Input (Count Source Input in Event Counter Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TB)}$	TBi_{IN} Input Cycle Time (counted on one edge)	100		ns
$t_{w(TBH)}$	TBi_{IN} Input High ("H") Width (counted on one edge)	40		ns
$t_{w(TBL)}$	TBi_{IN} Input Low ("L") Width (counted on one edge)	40		ns
$t_{c(TB)}$	TBi_{IN} Input Cycle Time (counted on both edges)	200		ns
$t_{w(TBH)}$	TBi_{IN} Input High ("H") Width (counted on both edges)	80		ns
$t_{w(TBL)}$	TBi_{IN} Input Low ("L") Width (counted on both edges)	80		ns

Table 5.35 Timer B Input (Pulse Period Measurement Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TB)}$	TBi_{IN} Input Cycle Time	400		ns
$t_{w(TBH)}$	TBi_{IN} Input High ("H") Wdth	200		ns
$t_{w(TBL)}$	TBi_{IN} Input Low ("L") Width	200		ns

Table 5.36 Timer B Input (Pulse Width Measurement Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TB)}$	TBi_{IN} Input Cycle Time	400		ns
$t_{w(TBH)}$	TBi_{IN} Input High ("H") Width	200		ns
$t_{w(TBL)}$	TBi_{IN} Input Low ("L") Width	200		ns

Table 5.37 A/D Trigger Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(AD)}$	$\overline{ADTRG}$ Input Cycle Time (required for trigger)	1000		ns
$t_{w(ADL)}$	$\overline{ADTRG}$ Input Low ("L") Width	125		ns

Table 5.38 Serial I/O

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(CK)}$	CLKi Input Cycle Time	200		ns
$t_{w(CKH)}$	CLKi Input High ("H") Width	100		ns
$t_{w(CKL)}$	CLKi Input Low ("L") Width	100		ns
$t_{d(C-Q)}$	TxDi Output Delay Time		80	ns
$t_{h(C-Q)}$	TxDi Hold Time	0		ns
$t_{su(D-C)}$	RxDi Input Setup Time	30		ns
$t_{h(C-Q)}$	RxDi Input Hold Time	90		ns

Table 5.39 External Interrupt $\overline{INTi}$ Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{w(INH)}$	$\overline{INTi}$ Input High ("H") Width	250		ns
$t_{w(INL)}$	$\overline{INTi}$ Input Low ("L") Width	250		ns

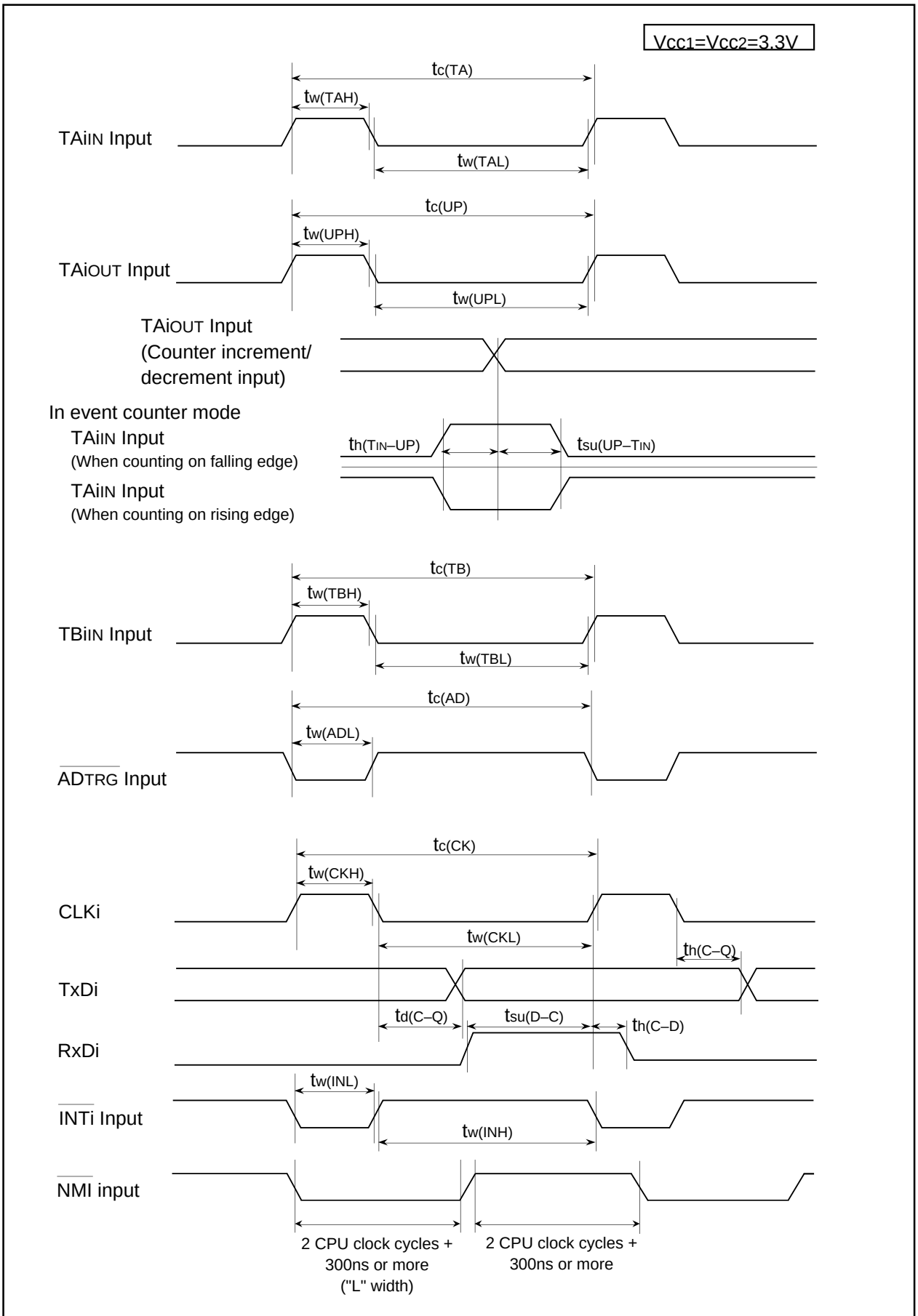


Figure 5.9 Vcc1=Vcc2=3.3V Timing Diagram (3)

$V_{CC1}=V_{CC2}=5V$

Table 5.45 A/D Conversion Characteristics ($V_{CC1}=V_{CC2}=4.2$ to 5.5V, $V_{SS}=0V$ at Topr= -40 to 85°C (T version), f(BCLK)=32MHz unless otherwise specified)

Symbol	Parameter	Measurement Condition		Standard			Unit
				Min.	Typ.	Max.	
-	Resolution	$V_{REF}=V_{CC1}$				10	Bits
INL	Integral Nonlinearity Error	$V_{REF}=V_{CC1}=V_{CC2}=5V$	AN_0 to AN_7, $AN0_0$ to $AN0_7$, $AN2_0$ to $AN2_7$, $AN15_0$ to $AN15_7$, ANEX0, ANEX1			±3	LSB
							LSB
			External op-amp connection mode			±7	LSB
							LSB
DNL	Differential Nonlinearity Error					±1	LSB
-	Offset Error					±3	LSB
-	Gain Error					±3	LSB
R_{LADDER}	Resistor Ladder	$V_{REF}=V_{CC1}$		8		40	kΩ
t_{CONV}	10-bit Conversion Time(1, 2)			2.06			µs
t_{CONV}	8-bit Conversion Time(1, 2)			1.75			µs
t_{SAMP}	Sampling Time(1)			0.188			µs
V_{REF}	Reference Voltage			2		V_{CC1}	V
V_{IA}	Analog Input Voltage			0		V_{REF}	V

NOTES:
1. Divide f(X_{IN}), if exceeding 16 MHz, to keep ϕAD frequency at 16 MHz or less.
2. With using the sample and hold function.

Table 5.46 D/A Conversion Characteristics ($V_{CC1}=V_{CC2}=4.2$ to 5.5V, $V_{SS}=0V$ at Topr= -40 to 85°C (T version), f(BCLK)=32MHz unless otherwise specified)

Symbol	Parameter	Measurement Condition	Standard			Unit
			Min.	Typ.	Max.	
-	Resolution				8	Bits
-	Absolute Accuracy				1.0	%
t_{SU}	Setup Time				3	µs
R_O	Output Resistance		4	10	20	kΩ
I_{VREF}	Reference Power Supply Input Current	(Note 1)			1.5	mA

NOTES:
1. Measurement when using one D/A converter. The DAi register (i=0, 1) of the D/A converter, not being used, is set to "00_{16}". The resistor ladder in the A/D converter is excluded.
I_{VREF} flows even if the VCUT bit in the AD0CON1 register is set to "0" (no V_{REF} connection).

REVISION HISTORY	M32C/85 Group (M32C/85, M32C/85T) Datasheet

Rev.	Date	Description	
		Page	Summary
0.30	Jul.18, 2003	–	New Document
0.40	Sep.30, 2003		**Overview**
		2 to 3	• **Tables 1.1 and 1.2 M32C/85 Performance** "Oscillator Stop Detect Function" added
		5	• **Figure 1.2 ROM/RAM Capacity** and **Table 1.3. M32C/85 Group** M30852ME-XXXGP and M30850ME-XXXGP/FP deleted
		6	• ROM capacity "192 Kbytes" deleted
		7, 11, 12	• **Figures 1.4** to **1.6 Pin Assignments** Note 2 added
		10,14	- VREF pin changed from analog input pins to control pins.
		16 to 18	- SDA0 to SDA4 pins changed from output pins to I/O pins.
		17	- TA4OUT changed from input pin to I/O pin. - TA4IN pin changed from output pin to input pin. - ISRxD1 pin modified to ISRxD0 pin in port P8.
		18	- DA0 and DA1 pins changed from input pins to output pins.
		19	- Symbol "P117" modified to "P114" and description from "8-bit" to "5-bit". - Descriptions of ISTxD1 and BE1IN modified from "received data" to "transmit data".
			SFR
		44,45	- Notes written directly in the Tables.
0.50	Feb.05, 2004		**Overview**
		2, 3	• **Tables 1.1 and 1.2 M32C/85 Performance** "Shortest Instruction Execution Time" and "Power Comsumption" values modified
			Memory
		23	• **Figure 3.1 Memory Map** Diagram modified
			SFR
		24	• "After RESET" values of PM 1, PM 2, D4INT, G0IRF, G1IRF, IDB0 to IDB1, TA0MR to TA4MR, TCSPR, DM0SL to DM3SL registers corrected • NOTES added to PM0 and TCSPR registers
			Electrical Characteristics
			• Newly added
0.51	Feb.09, 2004		**Electrical Characteristics**
		52	• **Table 5.6 Flash Memory Version Electrical Characteristics** Note 4 changed
		59	• **Figure 5.2 Vcc1=Vcc2=5V Timing Diagram (1)** Notes 1 and 2 changed
		60	• **Figure 5.3 Vcc1=Vcc2=5V Timing Diagram (2)** Notes 1, 2, and 3 changed
		70	• **Figure 5.6 Vcc1=Vcc2=3.3V Timing Diagram (1)** Notes 1, 2, and 3 changed
		71	• **Figure 5.7 Vcc1=Vcc2=3.3V Timing Diagram (2)** Notes 1 and 2 changed
0.52	Mar.12, 2004		**Overview**
		2, 3	• **Table 1.1 and 1.2 M32C/85 Group Performance** Value of Power Consumption modified

REVISION HISTORY	M32C/85 Group (M32C/85, M32C/85T) Datasheet

Rev.	Date	Description	
		Page	Summary
			Electrical Characteristics
		50	• **Table 5.3 Electrical Characteristics** Maximum values for Power Supply Current modified
		52	• **Table 5.6 Flash Memory Version Electrical Characteristics** Note 1. 100-cycle Products (D3, D5, U3, U5) deleted; Note 4 modified
			• **Table 5.7 Flash Memory Version Program and Erase Voltage and Read Operation Voltage Characteristics (at Topr=0 to 60°C)** deleted
		63	• **Table 5.22 Electrical Characteristics** Maximum values for Power Supply Consumption modified and standard values when "Topr=85°C while clock is stopped" deleted
1.00	Jun.01, 2004	-	**M32C/85T (High-reliability version)** added
		All Pages	Words standardized: On-chip oscillator, A/D converter and D/A converter
			Overview
		1	• **1.1 Applications** Automobiles added
		2, 3	• **Table 1.1** and **Table 1.2 M32C/85 Group (M32C/85, M32C/85T) Performance** M32C/85T added; note 3 added
		4	• **Figure 1.1 M32C/85 Group (M32C/85, M32C/85T) Block Diagram** Note 3 added
		5	• **1.4 Product Information** Description modified
			• **Figure 1.2 ROM/RAM Capacity** figure modified
		5, 6	• **Table 1.3 M32C/85 Group** M32C/85T added
		6	• **Figure 1.3 Product Numbering System** M32C/85T added
		7	• **Figure 1.4 Pin Assignment for 144-Pin Package** Note 3 added
		12	• **Figure 1.6 Pin Assignment for 100-Pin Pacakage** Note 5 added
		8 to 10	• **Table 1.5 Pin Characteristics for 144-Pin Package** Note 1 added
		13, 14	• **Table 1.6 Pin Characteristics for 100-Pin Package** Note 1 added
		15 to 18	• **Table 1.7 Pin Description** Notes added
			Memory
		22	• **Figure 3.1 Memory Map** Tables of internal ROM/internal RAM modified; note 2 modified; notes 4 and 5 added
			SFR
		23	• Note 2 added
		24	• PWCR0 and PWCR1 registers deleted
			• "Values after RESET" of the masked ROM version added to the FMR0 register
			• Note 1 added
			Electrical Characteristics
		46	• **Table 5.2 Recommended Operating Conditions** $f_{(ripple)}$, $V_{p-p(ripple)}$, V_{CC}, SV_{CC} and note 1 deleted
		47	• **Table 5.3 Electrical Characteristics** R_{PULLUP} value for the masked ROM version added